TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSIV)

2SK3566

Switching Regulator Applications

TOSHIBA

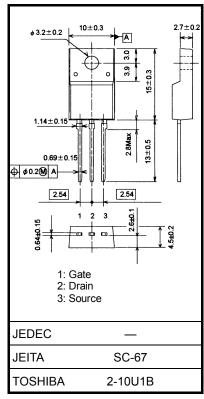
Low drain-source ON-resistance: R_{DS} (ON) = 5.6 Ω (typ.)

• High forward transfer admittance: |Y_{fs}| = 2.0 S (typ.)

Absolute Maximum Ratings (Ta = 25°C)

- Low leakage current: I_{DSS} = 100 μ A (max) (V_{DS} = 720 V)
- Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Characteristics Symbol Rating Unit Drain-source voltage 900 ٧ VDSS 900 v Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) VDGR V Gate-source voltage VGSS ± 30 DC (Note 1) I_D 2.5 Drain current Α Pulse (t = 1 ms) 7.5 IDP (Note 1) Drain power dissipation (Tc = 25°C) w P_D 40 Single pulse avalanche energy E_{AS} 216 mJ (Note 2) Avalanche current 25 А I_{AR} 4 Repetitive avalanche energy (Note 3) E_{AR} mJ °C Channel temperature T_{ch} 150 -55 to 150 °C Storage temperature range Tstg



Weight : 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

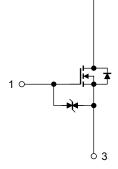
Characteristics	Symbol	Max	Unit	
Thermal resistance, channel to case	R _{th (ch-c)}	3.125	°C/W	
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W	

Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2: $V_{DD} = 90 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}, \text{ L} = 63.4 \text{ mH}, \text{ I}_{AR} = 2.5 \text{ A}, \text{ R}_{G} = 25 \Omega$

Note 3: Repetitive rating: Pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.



Start of commercial production 2002-06

02

Unit: mm

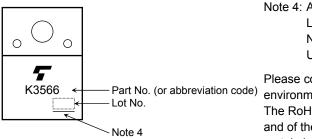
Electrical Characteristics (Ta = 25°C)

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cui	rrent	I _{GSS}	$V_{GS}=\pm 25~V,~V_{DS}=0~V$	_		±10	μA
Gate-source breakdown voltage		V (BR) GSS	$I_G=\pm 10~\mu A,~V_{DS}=0~V$	±30			V
Drain cut-off curr	ent	I _{DSS}	$V_{DS} = 720 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			100	μA
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	900		_	V
Gate threshold ve	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0		4.0	V
Drain-source ON	-resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 1.5 \text{ A}$		5.6	6.4	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 20 \text{ V}, \text{ I}_{D} = 1.5 \text{ A}$	1.0	2.0		S
Input capacitance	e	C _{iss}		_	470		
Reverse transfer capacitance		C _{rss}	V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz	_	10		pF
Output capacitance		C _{oss}			50		
Switching time	Rise time	tr	V_{GS} $0 V$ V_{GS} $0 V$ V_{GS} $0 V$	_	20	_	• ns
	Turn-on time	t _{on}		_	60	_	
	Fall time	t _f			30	_	
	Turn-off time	t _{off}	Duty \leq 1%, $t_W =$ 10 μs		100	—	
Total gate charge Q _g		Qg		_	12		
Gate-source charge		Qgs	$V_{DD} \approx 400 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 2.5 \text{ A}$		7		nC
Gate-drain charge		Q _{gd}			5		

Source-Drain Ratings and Characteristics (Ta = 25°C)

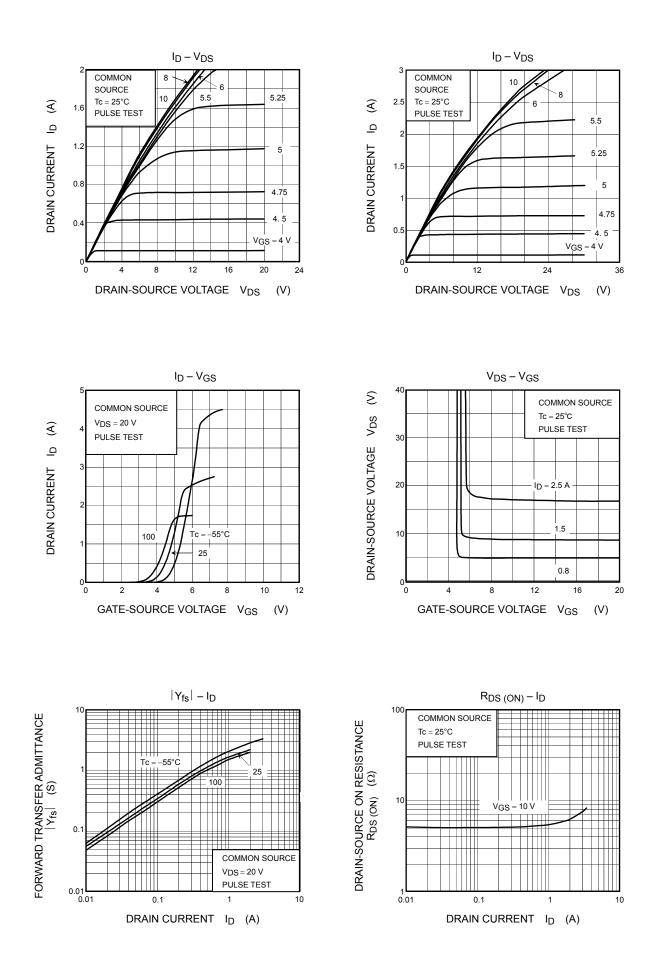
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	2.5	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_		7.5	А
Forward voltage (diode)	V _{DSF}	$I_{DR} = 2.5 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 2.5 \text{ A}, V_{GS} = 0 \text{ V},$	_	720	_	ns
Reverse recovery charge	Qrr	dl _{DR} /dt = 100 A/μs	_	3.6		μC

Marking

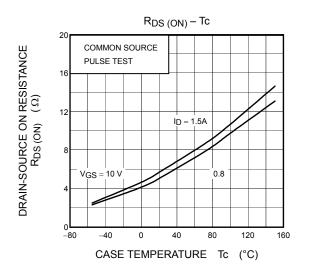


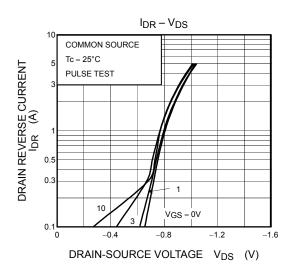
Note 4: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]] Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of

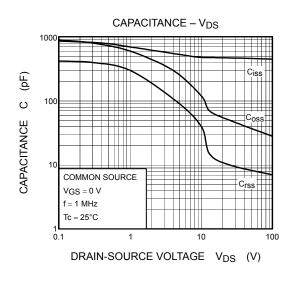
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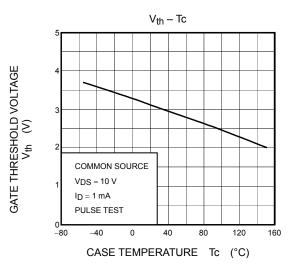


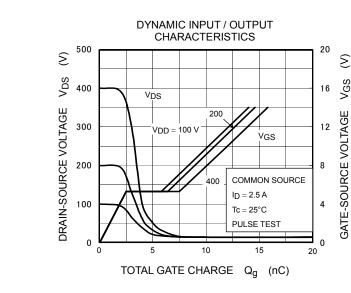
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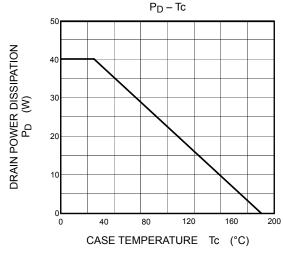


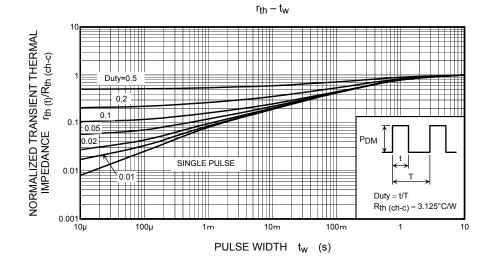


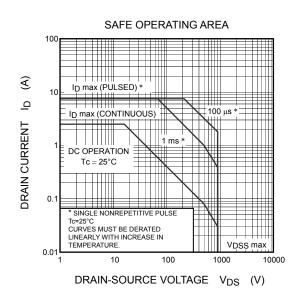


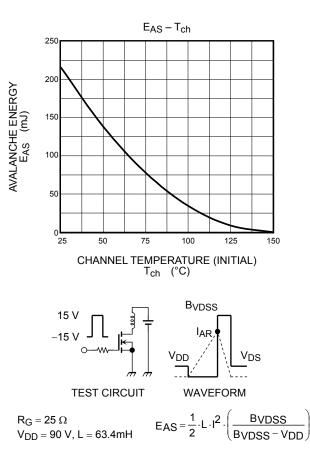












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